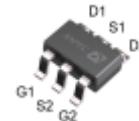


Dual Enhancement Mode MOSFET (N and P-Channel)

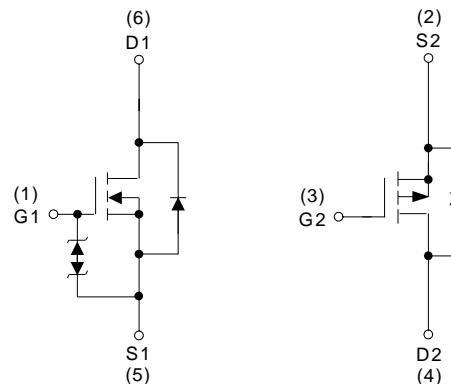
Features

- N-Channel
20V/1.8A,
 $R_{DS(ON)}=170m\Omega$ (typ.) @ $V_{GS}=4.5V$
 $R_{DS(ON)}=270m\Omega$ (typ.) @ $V_{GS}=2.5V$
- P-Channel
-20V/-1.2A,
 $R_{DS(ON)}=360m\Omega$ (typ.) @ $V_{GS}=-4.5V$
 $R_{DS(ON)}=530m\Omega$ (typ.) @ $V_{GS}=-2.5V$
- Super High Dense Cell Design
- Reliable and Rugged
- Lead Free Available (RoHS Compliant)

Pin Description



Top View of SOT-26



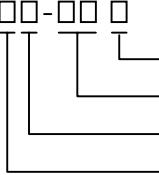
N-Channel MOSFET

P-Channel MOSFET

Applications

- Power Management in Notebook Computer, Portable Equipment and Battery Powered Systems

Ordering and Marking Information

APM2700C □□-□□ □  Lead Free Code Handling Code Temp. Range Package Code	Package Code C : SOT-26 Operating Junction Temp. Range C : -55 to 150°C Handling Code TU : Tube TR : Tape & Reel Lead Free Code L : Lead Free Device Blank : Original Device
APM2700C C : M70X	XXXXX - Date Code

Note: ANPEC lead-free products contain molding compounds/die attach materials and 100% matte in plate termination finish; which are fully compliant with RoHS and compatible with both SnPb and lead-free soldering operations. ANPEC lead-free products meet or exceed the lead-free requirements of IPC/JEDEC J STD-020C for MSL classification at lead-free peak reflow temperature.

ANPEC reserves the right to make changes to improve reliability or manufacturability without notice, and advise customers to obtain the latest version of relevant information to verify before placing orders.

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	N Channel	P Channel	Unit
V_{DSS}	Drain-Source Voltage	20	-20	V
V_{GSS}	Gate-Source Voltage	± 8	± 8	
I_D^*	Continuous Drain Current	$V_{GS}=\pm 4.5\text{V}$	1.8	A
I_{DM}^*	300 μs Pulsed Drain Current		6	
I_S^*	Diode Continuous Forward Current	1	-1	A
T_J	Maximum Junction Temperature	150		$^\circ\text{C}$
T_{STG}	Storage Temperature Range	-55 to 150		
P_D^*	Power Dissipation	$T_A=25^\circ\text{C}$	0.83	W
		$T_A=100^\circ\text{C}$	0.3	
$R_{\theta JA}^*$	Thermal Resistance-Junction to Ambient	150		$^\circ\text{C}/\text{W}$

Note:

*Surface Mounted on 1in² pad area, t ≤ 10sec.

Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Test Condition	APM2700C			Unit
			Min.	Typ.	Max.	
Static Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0\text{V}, I_{DS}=250\mu\text{A}$	N-Ch	20		V
		$V_{GS}=0\text{V}, I_{DS}=-250\mu\text{A}$	P-Ch	-20		
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS}=16\text{V}, V_{GS}=0\text{V}$ $T_J=85^\circ\text{C}$	N-Ch		1	μA
					30	
		$V_{DS}=-16\text{V}, V_{GS}=0\text{V}$ $T_J=85^\circ\text{C}$	P-Ch		-1	
					-30	
$V_{GS(\text{th})}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_{DS}=250\mu\text{A}$	N-Ch	0.45	0.6	V
		$V_{DS}=V_{GS}, I_{DS}=-250\mu\text{A}$	P-Ch	-0.45	-0.6	
I_{GSS}	Gate Leakage Current	$V_{GS}=\pm 8\text{V}, V_{DS}=0\text{V}$	N-Ch		± 2	μA
		$V_{GS}=\pm 8\text{V}, V_{DS}=0\text{V}$	P-Ch		± 100	
$R_{DS(\text{ON})}^{\text{a}}$	Drain-Source On-State Resistance	$V_{GS}=4.5\text{V}, I_{DS}=1.8\text{A}$	N-Ch		170	$\text{m}\Omega$
		$V_{GS}=-4.5\text{V}, I_{DS}=-1.2\text{A}$	P-Ch		360	
		$V_{GS}=2.5\text{V}, I_{DS}=0.9\text{A}$	N-Ch		270	
		$V_{GS}=-2.5\text{V}, I_{DS}=-0.7\text{A}$	P-Ch		530	

Electrical Characteristics (Cont.) ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Test Condition	APM2700C			Unit		
			Min.	Typ.	Max.			
Static Characteristics (Cont.)								
V_{SD}^a	Diode Forward Voltage	$I_{SD}=0.5\text{A}, V_{GS}=0\text{V}$	N-Ch		0.8	1.3	V	
		$I_{SD}=-0.5\text{A}, V_{GS}=0\text{V}$	P-Ch		-0.8	-1.3		
Dynamic Characteristics ^b								
C_{iss}	Input Capacitance	N-Channel $V_{GS}=0\text{V}, V_{DS}=20\text{V},$ Frequency=1.0MHz	N-Ch		130		pF	
			P-Ch		140			
C_{oss}	Output Capacitance	P-Channel $V_{GS}=0\text{V}, V_{DS}=-20\text{V},$ Frequency=1.0MHz	N-Ch		25			
			P-Ch		40			
C_{rss}	Reverse Transfer Capacitance		N-Ch		15			
			P-Ch		30			
$t_{d(ON)}$	Turn-on Delay Time	N-Channel $V_{DD}=10\text{V}, R_L=10\Omega, I_{DS}=1\text{A}, V_{GEN}=4.5\text{V}, R_G=6\Omega$	N-Ch		2	4	ns	
			P-Ch		3	6		
T_r	Turn-on Rise Time		N-Ch		17	32		
			P-Ch		18	33		
$t_{d(OFF)}$	Turn-off Delay Time	P-Channel $V_{DD}=-10\text{V}, R_L=10\Omega, I_{DS}=-1\text{A}, V_{GEN}=-4.5\text{V}, R_G=6\Omega$	N-Ch		4	8		
			P-Ch		10	19		
T_f	Turn-off Fall Time		N-Ch		18	33		
			P-Ch		20	37		
Gate Charge Characteristics ^b								
Q_g	Total Gate Charge	N-Channel $V_{DS}=10\text{V}, V_{GS}=4.5\text{V}, I_{DS}=1.8\text{A}$	N-Ch		4.2	5.5	nC	
			P-Ch		7	9		
Q_{gs}	Gate-Source Charge		N-Ch		0.6			
			P-Ch		1.1			
Q_{gd}	Gate-Drain Charge		N-Ch		0.6			
			P-Ch		1.1			

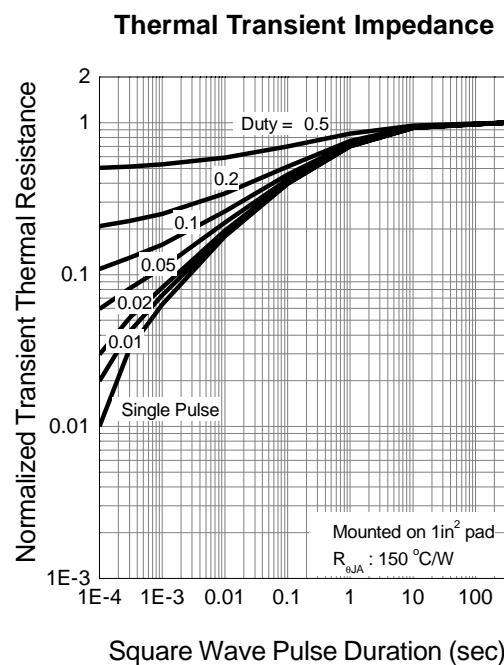
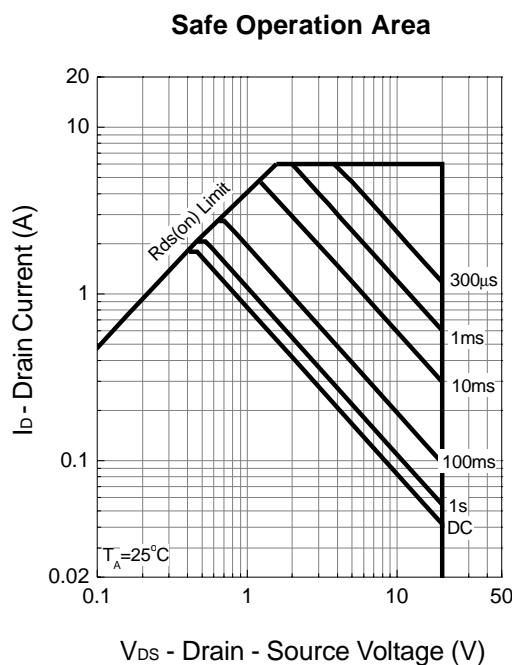
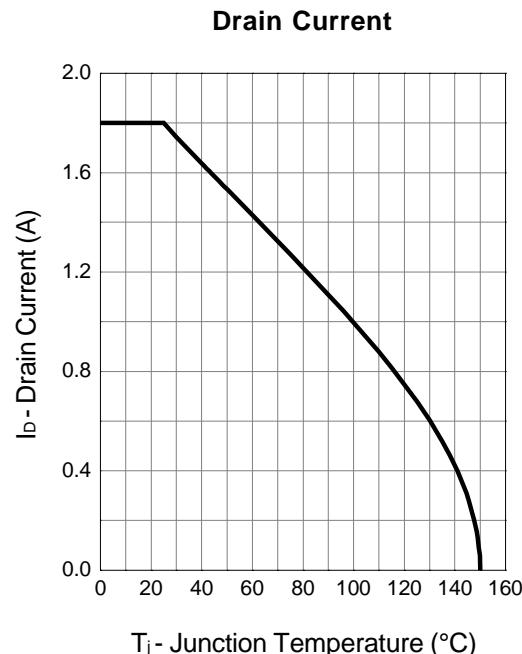
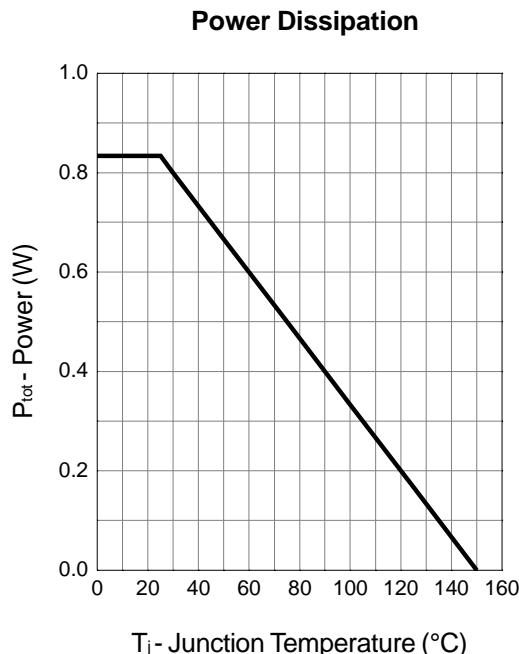
Notes:

a : Pulse test ; pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.

b : Guaranteed by design, not subject to production testing.

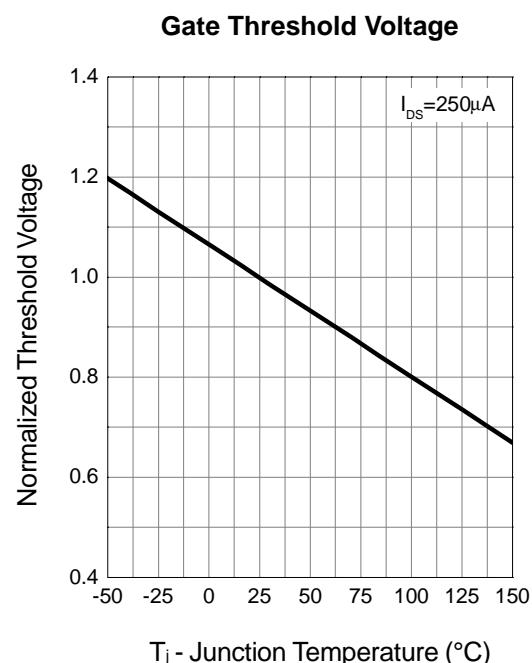
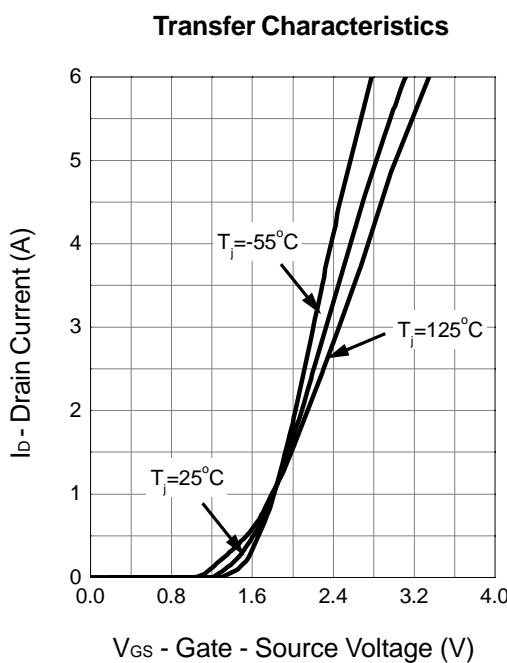
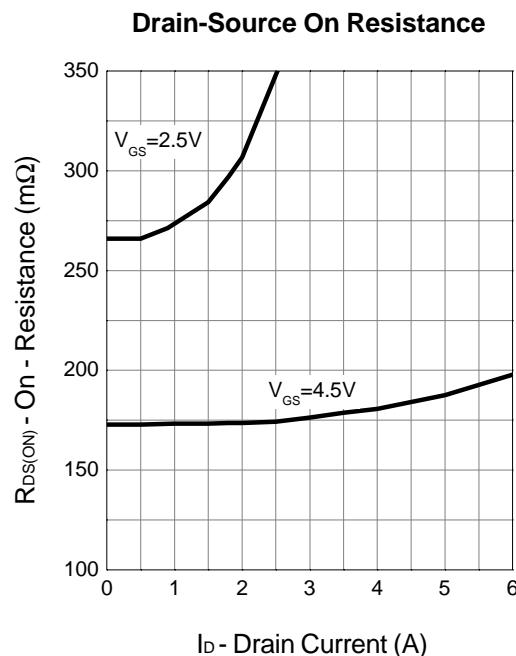
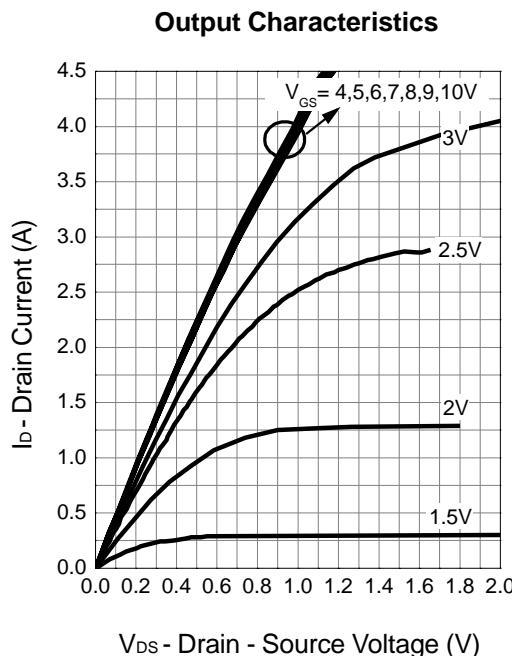
Typical Characteristics

N-Channel



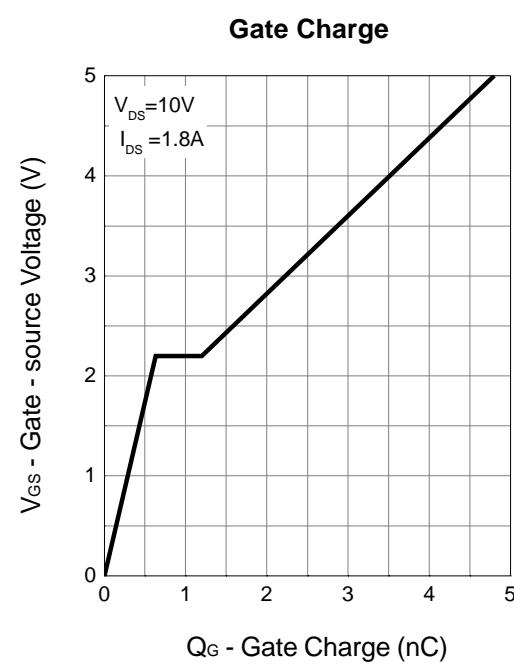
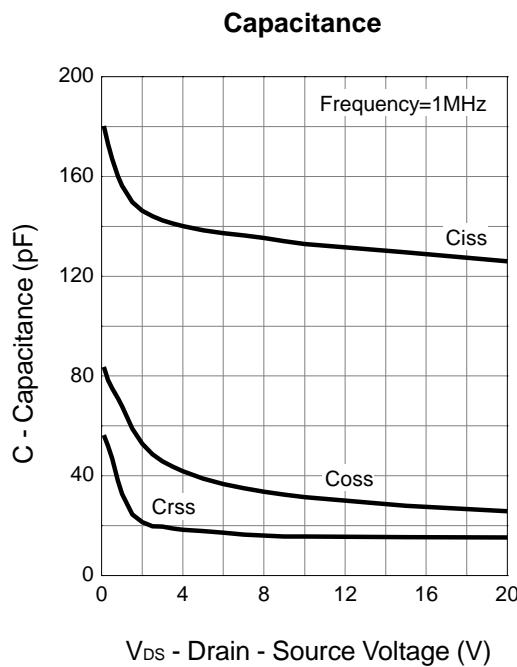
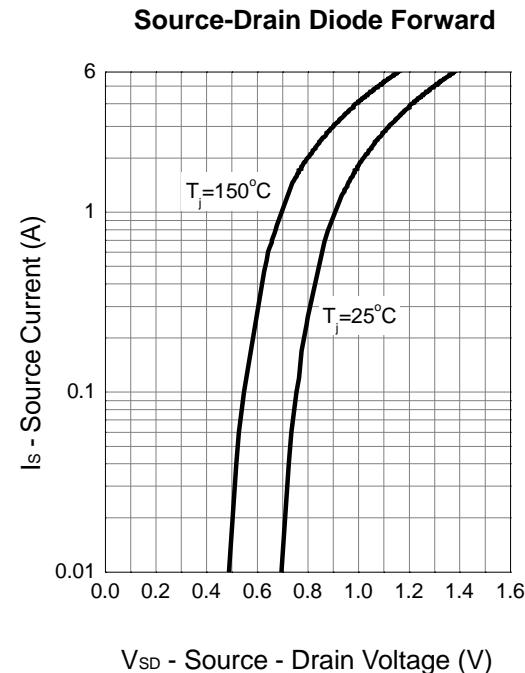
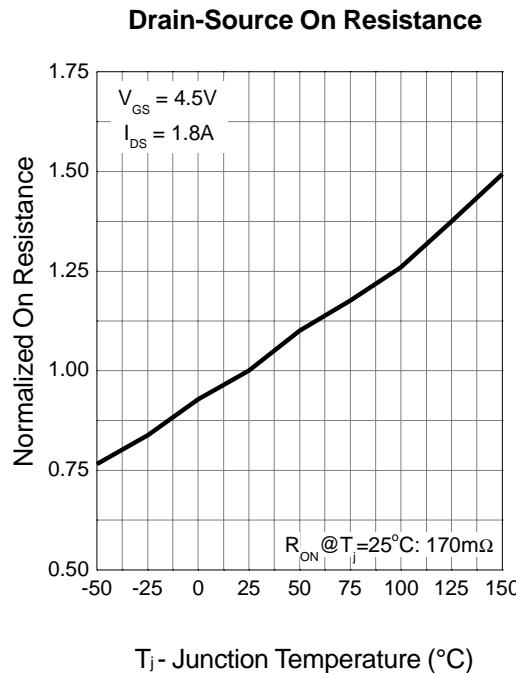
Typical Characteristics (Cont.)

N-Channel



Typical Characteristics (Cont.)

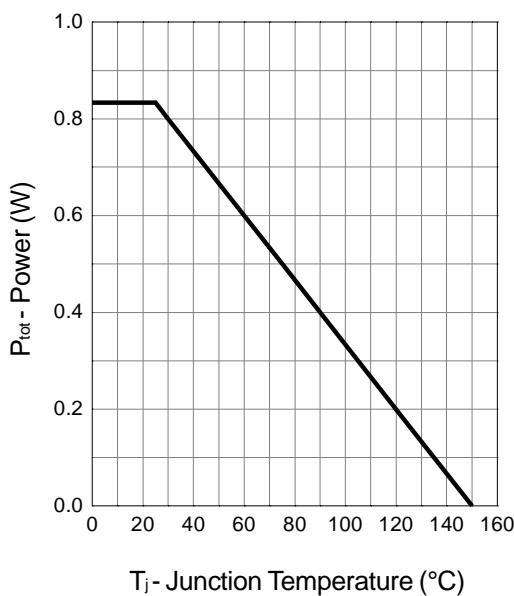
N-Channel



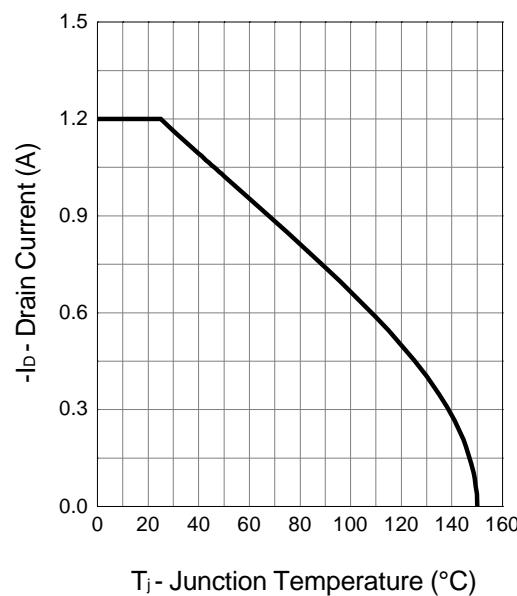
Typical Characteristics

P-Channel

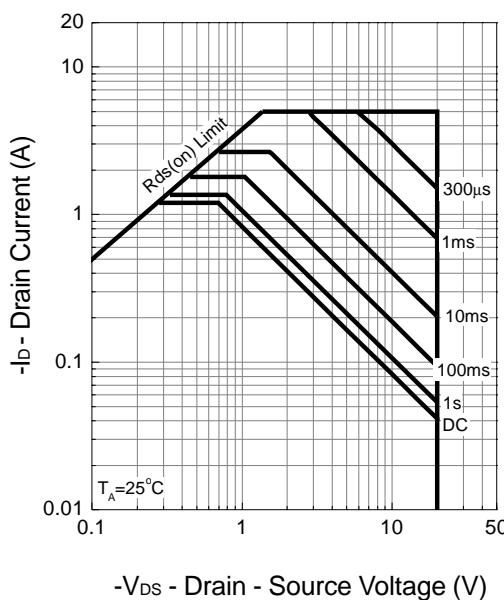
Power Dissipation



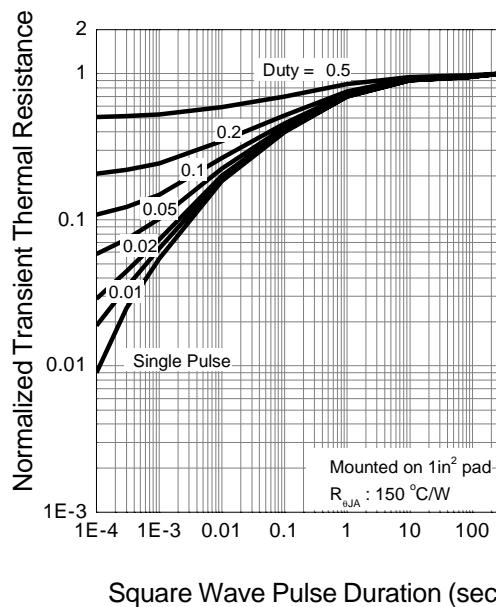
Drain Current



Safe Operation Area



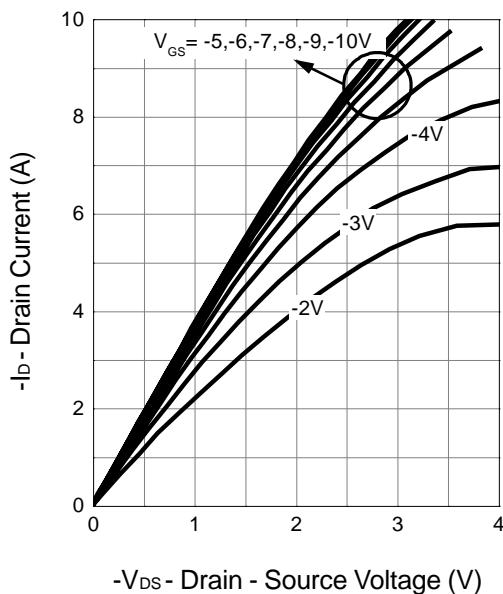
Thermal Transient Impedance



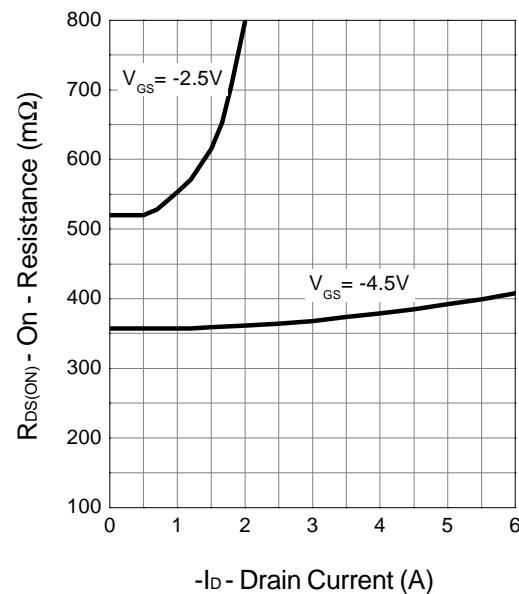
Typical Characteristics (Cont.)

P-Channel

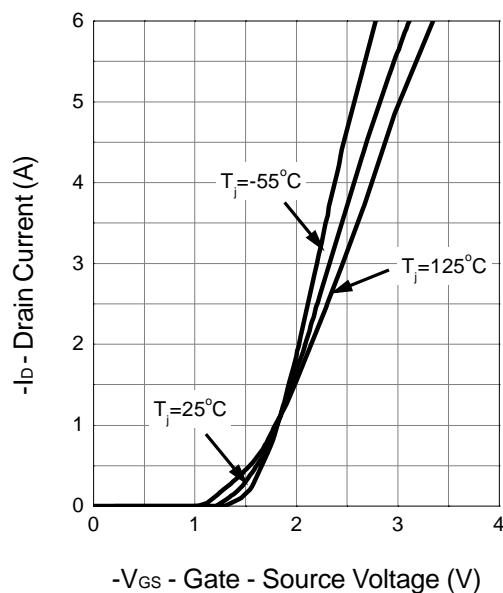
Output Characteristics



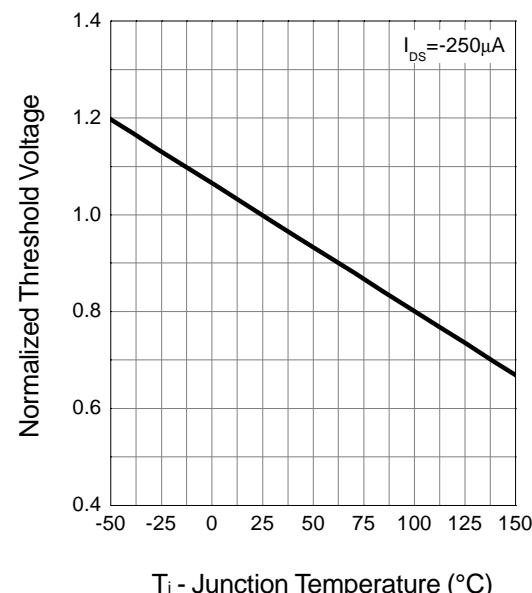
Drain-Source On Resistance



Transfer Characteristics

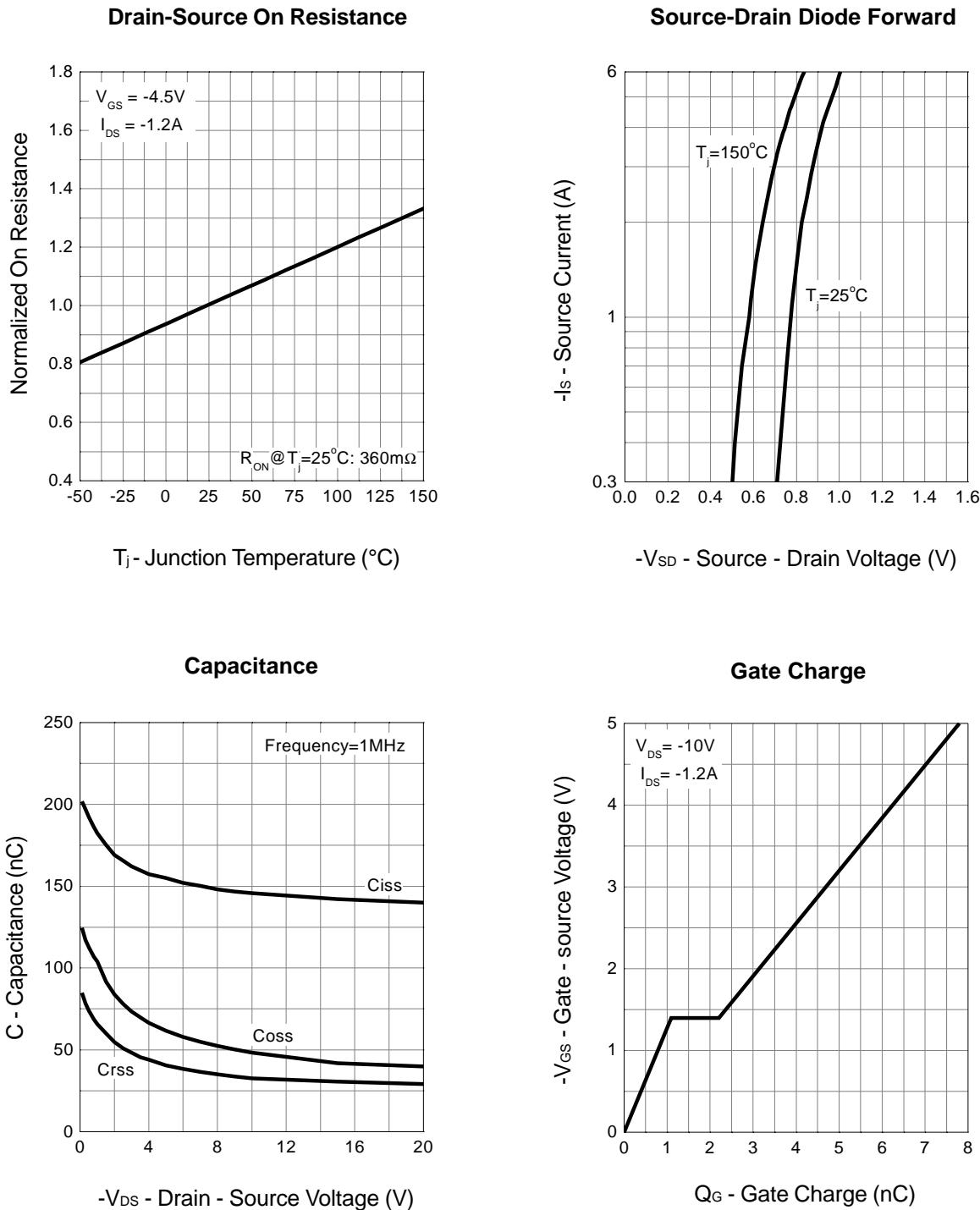


Gate Threshold Voltage



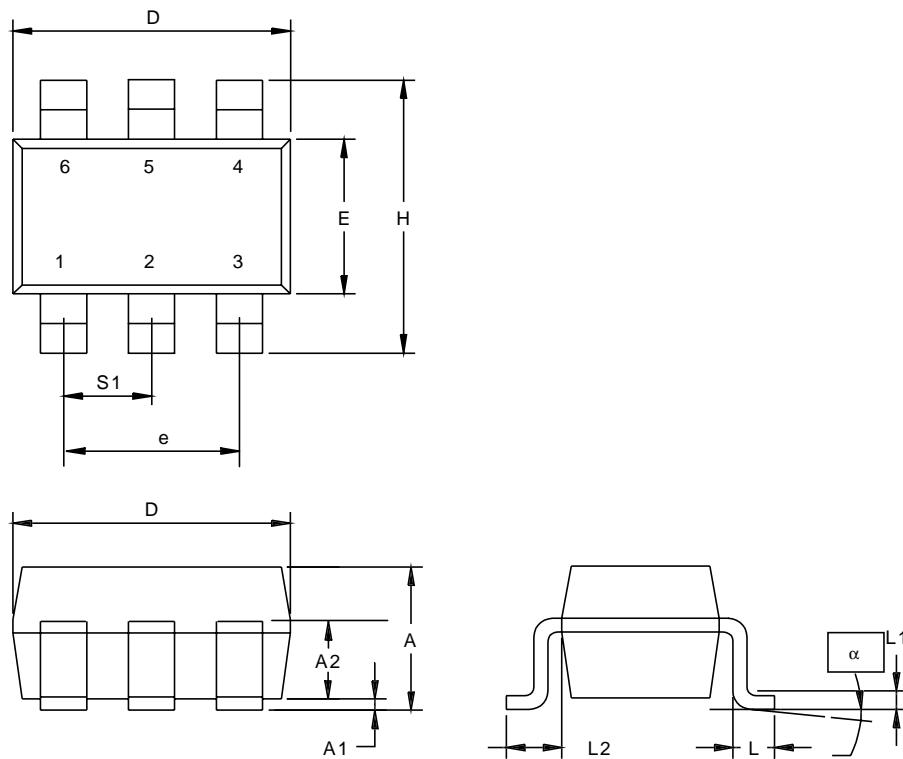
Typical Characteristics (Cont.)

P-Channel



Packaging Information

SOT-23-6

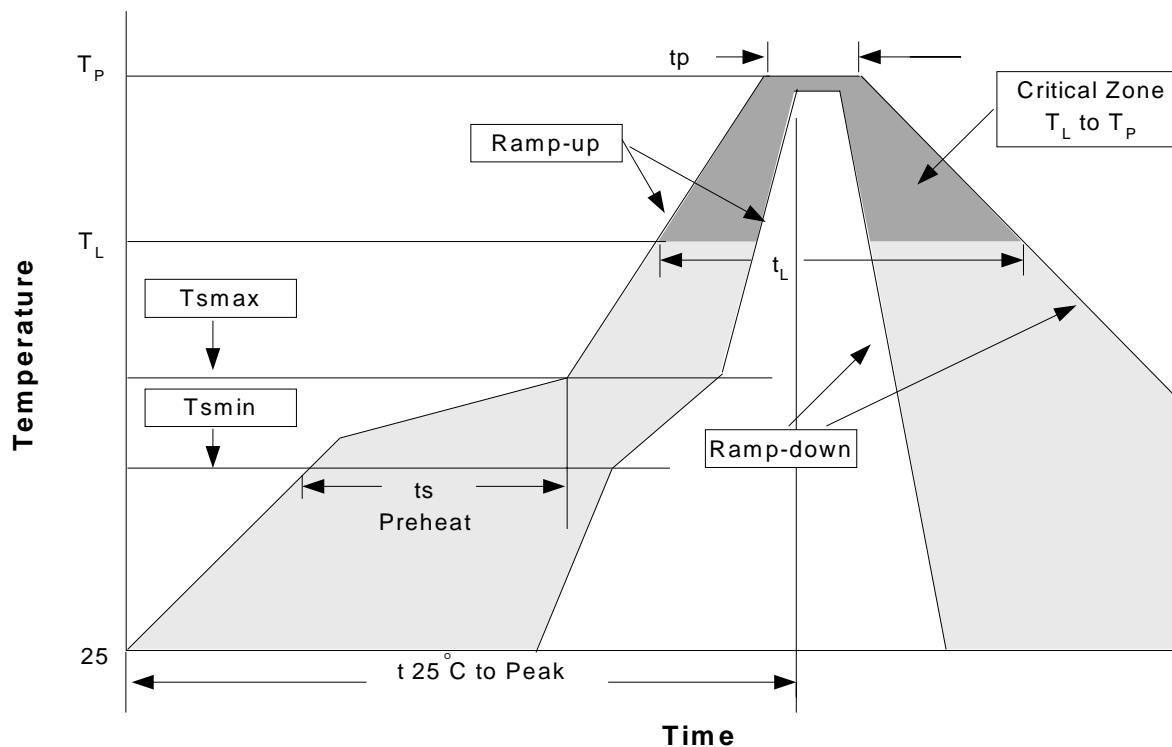


Dim	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	1.00	1.45	0.0394	0.0571
A1	0.00	0.15	0.0000	0.0591
A2	0.70	1.25	0.0276	0.0492
b	0.35	0.55	0.0138	0.0217
D	2.70	3.10	0.1063	0.1220
E	1.40	1.80	0.50551	0.0709
e	1.90 BSC		0.07480 BSC	
H	2.60	3.00	0.1024	0.1181
L	0.30	-	0.00118	-
L1	0.08	0.25	0.0031	0.0098
L2	0.60 REF		0.024 REF	
α	0°	10°	0°	10°
S1	0.85	1.05	0.0335	0.0413

Physical Specifications

Terminal Material	Solder-Plated Copper (Solder Material : 90/10 or 63/37 SnPb), 100%Sn
Lead Solderability	Meets EIA Specification RSI86-91, ANSI/J-STD-002 Category 3.

Reflow Condition (IR/Convection or VPR Reflow)



Classification Reflow Profiles

Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate (T _L to T _P)	3°C/second max.	3°C/second max.
Preheat	<ul style="list-style-type: none"> - Temperature Min (T_{smin}) - Temperature Max (T_{smax}) - Time (min to max) (t_s) 	<ul style="list-style-type: none"> 100°C 150°C 60-120 seconds
Time maintained above:		
<ul style="list-style-type: none"> - Temperature (T_L) - Time (t_L) 	183°C 60-150 seconds	217°C 60-150 seconds
Peak/Classification Temperature (T _P)	See table 1	See table 2
Time within 5°C of actual Peak Temperature (t _P)	10-30 seconds	20-40 seconds
Ramp-down Rate	6°C/second max.	6°C/second max.
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

Notes: All temperatures refer to topside of the package .Measured on the body surface.

Classification Reflow Profiles(Cont.)

Table 1. SnPb Eutectic Process – Package Peak Reflow Temperatures

Package Thickness	Volume mm ³ <350	Volume mm ³ ≥350
<2.5 mm	240 +0/-5°C	225 +0/-5°C
≥2.5 mm	225 +0/-5°C	225 +0/-5°C

Table 2. Pb-free Process – Package Classification Reflow Temperatures

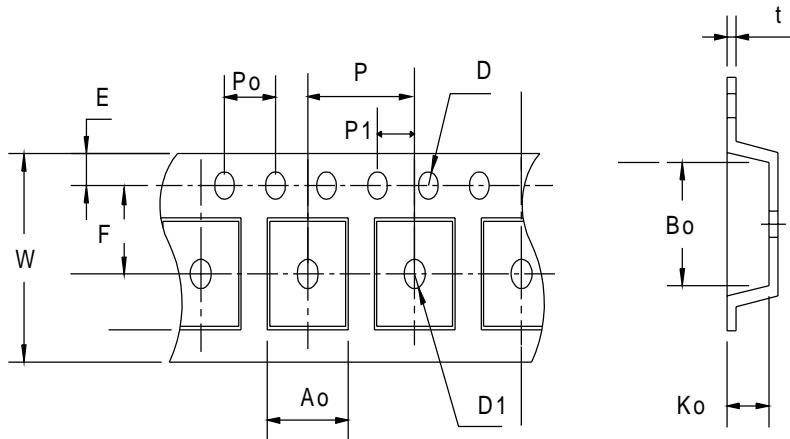
Package Thickness	Volume mm ³ <350	Volume mm ³ 350-2000	Volume mm ³ >2000
<1.6 mm	260 +0°C*	260 +0°C*	260 +0°C*
1.6 mm – 2.5 mm	260 +0°C*	250 +0°C*	245 +0°C*
≥2.5 mm	250 +0°C*	245 +0°C*	245 +0°C*

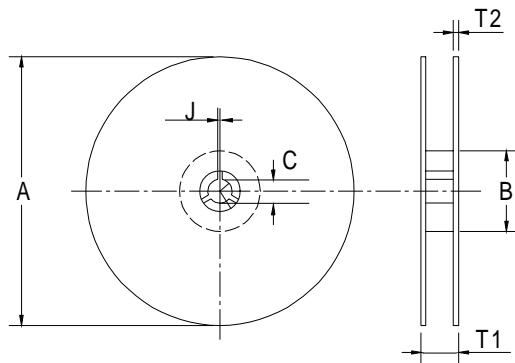
*Tolerance: The device manufacturer/supplier **shall** assure process compatibility up to and including the stated classification temperature (this means Peak reflow temperature +0°C. For example 260°C+0°C) at the rated MSL level.

Reliability Test Program

Test item	Method	Description
SOLDERABILITY	MIL-STD-883D-2003	245°C, 5 SEC
HOLT	MIL-STD 883D-1005.7	1000 Hrs Bias @ 125°C
PCT	JESD-22-B, A102	168 Hrs, 100% RH, 121°C
TST	MIL-STD 883D-1011.9	-65°C ~ 150°C, 200 Cycles

Carrier Tape & Reel Dimensions



Carrier Tape & Reel Dimensions(Cont.)

Application	A	B	C	J	T1	T2	W	P	E
SOT-23-6	178±1	72 ± 1.0	13.0 +0.2	2.5 ± 0.15	8.4 ± 2	1.5± 0.3	8.0+ 0.3 - 0.3	4 ± 0.1	1.75± 0.1
	F	D	D1	Po	P1	Ao	Bo	Ko	t
	3.5 ± 0.05	1.5 +0.1	1.5 +0.1	4.0 ± 0.1	2.0 ± 0.1	3.15 ± 0.1	3.2± 0.1	1.4± 0.1	0.2±0.03

(mm)

Cover Tape Dimensions

Application	Carrier Width	Cover Tape Width	Devices Per Reel
SOT-23-6	8	5.3	3000

Customer Service**Anpec Electronics Corp.**

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